

isc N-Channel MOSFET Transistor

TK22E10N1, ITK22E10N1

• FEATURES

- Low drain-source on-resistance:
 R_{DS}(on) ≤13.8mΩ. (V_{GS} = 10 V)
- Enhancement mode:
 Vth =2.0 to 4.0V (VDS = 10 V, ID=0.3mA)
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRITION

· Switching Voltage Regulators

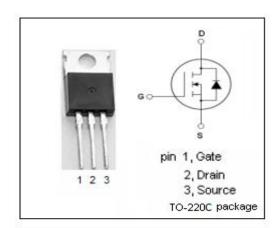


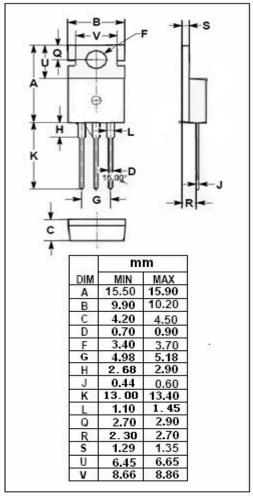
• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage	100	V
V _{GS}	Gate-Source Voltage	±20	V
I _D	Drain Current-Continuous	52	А
I _{DM}	Drain Current-Single Pulsed	102	А
P_D	Total Dissipation @T _C =25℃	72	W
Tj	Max. Operating Junction Temperature	150	${\mathbb C}$
T _{stg}	Storage Temperature	-55~150	${\mathbb C}$

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	1.72	°C/W
Rth(ch-a)	th(ch-a) Channel-to-ambient thermal resistance		°C/W







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ELECTRICAL CHARACTERISTICS

 T_{C} =25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D =10mA	100			V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =10V; I _D =0.3mA	2.0		4.0	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} =10V; I _D =11A			13.8	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±20V;V _{DS} = 0V			±0.1	μА
l _{DSS}	Drain-Source Leakage Current	V _{DS} =100V; V _{GS} = 0V			10	μА
V _{SDF}	Diode forward voltage	I _{DR} =22A, V _{GS} = 0 V			1.2	V

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